

Amendments to the Specification:

Please replace the paragraph beginning on page 21, line 7, with the following rewritten paragraph:

Evaluation with a conventional PZT ferroelectric film was done for comparison, the conventional PZT samples had Pb:Zr:Ti ratios of 1:0.2:0.8, 1:0.3:0.7, and 1:0.6:0.4. The leakage characteristics thereof are such that the leakage characteristics deteriorate with increasing ~~Pb~~-Ti content, as shown in Fig. 14, so that it is clear that when Ti is 80% and 2 V was applied, the characteristic was 10^{-5} A/cm², making it unsuitable for memory applications. Similarly, the fatigue characteristic deteriorated with increasing Ti content, as shown in Fig. 15. After imprinting, it was clear that most of the data could not be read, as shown in Fig. 16.